

## BDX54/A/B/C

### Hammer Drivers, Audio Amplifiers Applications Power Liner and Switching Applications

- Power Darlington TR
- Complement to BDX53, BDX53A, BDX53B and BDX53C respectively



1.Base 2.Collector 3.Emitter

## **PNP Epitaxial Silicon Transistor**

### Absolute Maximum Ratings T<sub>C</sub>=25°C unless otherwise noted

Symbol	Parameter	Value	Units
V <sub>CBO</sub>	Collector-Base Voltage : BDX54	- 45	V
	: BDX54A	- 60	V
	: BDX54B	- 80	V
	: BDX54C	- 100	V
V <sub>CEO</sub>	Collector-Emitter Voltage : BDX54	- 45	V
	: BDX54A	- 60	V
	: BDX54B	- 80	V
	: BDX54C	- 100	V
V <sub>EBO</sub>	Emitter-Base Voltage	- 5	V
I <sub>C</sub>	Collector Current (DC)	- 8	А
I <sub>CP</sub>	*Collector Current (Pulse)	- 12	А
I <sub>B</sub>	Base Current	- 0.2	А
P <sub>C</sub>	Collector Dissipation (T <sub>C</sub> =25°C)	60	W
T <sub>J</sub>	Junction Temperature	150	°C
T <sub>STG</sub>	Storage Temperature	- 65 ~ 150	°C

### Electrical Characteristics T<sub>C</sub>=25°C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
V <sub>CEO</sub> (sus)	* Collector-Emitter Sustaining Voltage					
	: BDX54	$I_C = -100 \text{mA}, I_B = 0$	- 45			V
	: BDX54A		- 60			V
	: BDX54B		- 80			V
	: BDX54C		- 100			٧
I <sub>CBO</sub>	Collector Cut-off Current : BDX54	$V_{CB} = -45V, I_{E} = 0$			- 200	μΑ
	: BDX54A	$V_{CB} = -60V, I_{E} = 0$			- 200	μΑ
	: BDX54B	$V_{CB} = -80V, I_{E} = 0$			- 200	μΑ
	: BDX54C	$V_{CB} = -100V, I_{E} = 0$			- 200	μΑ
I <sub>CEO</sub>	Collector Cut-off Current : BDX54	$V_{CE} = -22V, I_{B} = 0$			- 500	μΑ
	: BDX54A	$V_{CE} = -30V, I_{B} = 0$			- 500	μΑ
	: BDX54B	$V_{CE} = -40V, I_{B} = 0$			- 500	μΑ
	: BDX54C	$V_{CE} = -50V, I_{B} = 0$			- 500	μΑ
I <sub>EBO</sub>	Emitter Cut-off Current	$V_{EB} = -5V, I_{C} = 0$			- 2	mA
h <sub>FE</sub>	* DC Current Gain	$V_{CE} = -3V, I_{C} = -3A$	750			
V <sub>CE</sub> (sat)	* Collector-Emitter Saturation Voltage	$I_C = -3A$ , $I_B = -12mA$			- 2	V
V <sub>BE</sub> (sat)	* Base-Emitter Saturation Voltage	I <sub>C</sub> = - 3A, I <sub>B</sub> = - 12mA			- 2.5	V
V <sub>F</sub>	* Parallel Diode Forward Voltage	I <sub>F</sub> = - 3A		- 1.8	- 2.5	V
		I <sub>F</sub> = - 8A		- 2.5		V

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## **Typical Characteristics**

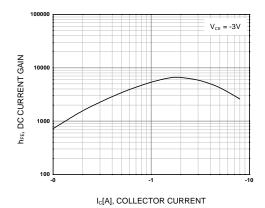


Figure 1. DC current Gain

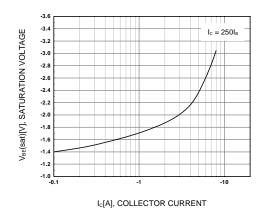


Figure 2. Base-Emitter Saturation Voltage

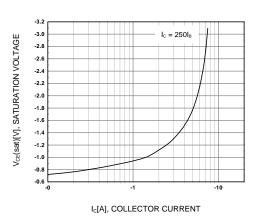


Figure 3. Collector-Emitter Saturation Voltage

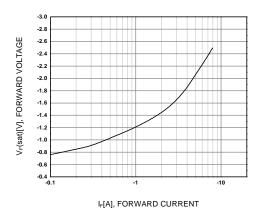


Figure 4. Damper Diode Forward Voltage

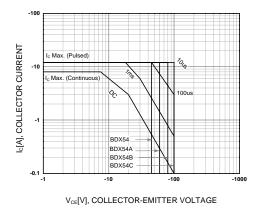


Figure 5. Safe Operating Area

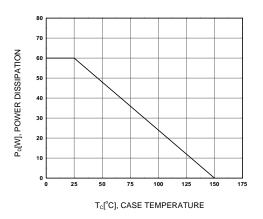
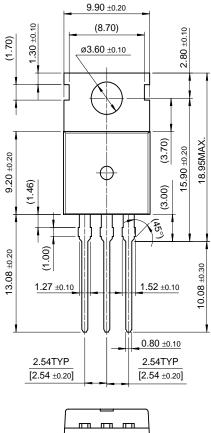


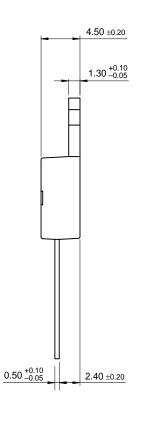
Figure 6. Power Derating

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# **Package Demensions**

## TO-220





10.00 ±0.20

Dimensions in Millimeters

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